

PNP Epitaxial Silicon Transistor

BSR16

PNP General Purpose Amplifier

- This Device Designed for Use as General Purpose Amplifier and Switches Requiring Collector Currents to 500 mA
- Sourced from Process 63
- See BCW68G for Characteristics

ABSOLUTE MAXIMUM RATINGS

($T_A = 25^\circ\text{C}$, unless otherwise specified.)

Symbol	Parameter	Value	Unit
V_{CEO}	Collector–Emitter Voltage	–60	V
V_{CBO}	Collector–Base Voltage	–60	V
V_{EBO}	Emitter–Base Voltage	–5.0	V
I_C	Collector Current – Continuous	–800	mA
T_J, T_{ST}	Operating and Storage Junction Temperature Range	–55 ~ +150	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. These ratings are based on a maximum junction temperature of 150°C .
2. These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

THERMAL CHARACTERISTICS

($T_A = 25^\circ\text{C}$, unless otherwise specified)

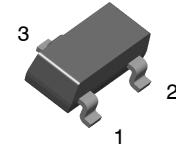
Symbol	Parameter	Max.	Unit
P_D	Total Device Dissipation Derate above 25°C	350 2.8	mW mW/ $^\circ\text{C}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	$^\circ\text{C}/\text{W}$

3. Device mounted on FR–4 PCB $40\text{ mm} \times 40\text{ mm} \times 1.5\text{ mm}$.



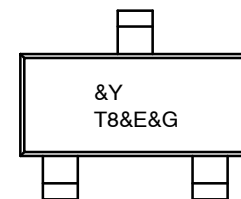
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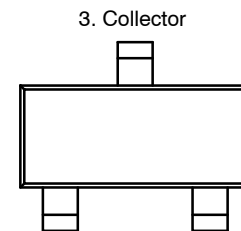
SOT–23
CASE 318BM

MARKING DIAGRAM



&Y ON Semiconductor Logo
T8 Specific Device Code
&E Designates Space
&G Date Code (Week)

PIN ASSIGNMENT



1. Base 2. Emitter

ORDERING INFORMATION

Device	Package	Shipping†
BSR16	SOT–23 (Pb–Free)	3,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

BSR16

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
$BV_{(BR)CEO}$	Collector–Emitter Breakdown Voltage	$I_C = -10\text{ mA}, I_B = 0$	-60			V
$BV_{(BR)CBO}$	Collector–Base Breakdown Voltage	$I_C = -100\ \mu\text{A}, I_E = 0$	-60			V
$BV_{(BR)EBO}$	Emitter–Base Breakdown Voltage	$I_E = -10\ \mu\text{A}, I_C = 0$	-5.0			V
I_{CBO}	Collector Cut–off Current	$V_{CB} = -50\text{ V}$ $V_{CB} = -50\text{ V}, T_A = 150^\circ\text{C}$			-10 -10	nA μA
I_{CEX}	Collector Cut–off Current	$V_{CE} = -30\text{ V}, V_{EB} = -0.5\text{ V}$			-50	nA
I_{BEX}	Reverse Base Current	$V_{CE} = -30\text{ V}, V_{EB} = -3.0\text{ V}$			-50	nA

ON CHARACTERISTICS

h_{FE}	DC Current Gain	$I_C = -0.1\text{ mA}, V_{CE} = -10\text{ V}$ $I_C = -1.0\text{ mA}, V_{CE} = -10\text{ V}$ $I_C = -10\text{ mA}, V_{CE} = -10\text{ V}$ $I_C = -150\text{ mA}, V_{CE} = -10\text{ V}$ $I_C = -500\text{ mA}, V_{CE} = -10\text{ V}$	75 100 100 100 50	300		
$V_{CE(sat)}$	Collector–Emitter Saturation Voltage	$I_C = -150\text{ mA}, I_B = -15\text{ mA}$ $I_C = -500\text{ mA}, I_B = -50\text{ mA}$			-0.4 -1.6	V
$V_{BE(sat)}$	Base–Emitter Saturation Voltage	$I_C = -150\text{ mA}, I_B = -15\text{ mA}$ $I_C = -500\text{ mA}, I_B = -50\text{ mA}$			-1.3 -2.6	V

SMALL SIGNAL CHARACTERISTICS

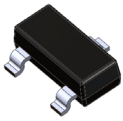
f_T	Current Gain Bandwidth Product	$I_C = -50\text{ mA}, V_{CE} = -20\text{ V},$ $f = 100\text{ MHz}, T_A = 25^\circ\text{C}$	200			MHz
C_{cb}	Output Capacitance	$V_{CB} = -10\text{ V}, I_E = 0, f = 1.0\text{ MHz}$			8.0	pF
C_{eb}	Emitter–Base Capacitance	$V_{CB} = -2.0\text{ V}, I_E = 0, f = 1.0\text{ MHz}$			30	pF

SWITCHING CHARACTERISTICS

t_{on}	Turn–On Time	$V_{CC} = -30\text{ V}, I_C = -150\text{ mA},$ $I_{B1} = -15\text{ mA}$			45	ns
t_d	Delay Time				10	ns
t_r	Rise Time				40	ns
t_{off}	Turn–Off Time	$V_{CC} = -6\text{ V}, I_C = -150\text{ mA},$ $I_{B1} = I_{B2} = -15\text{ mA}$			100	ns
t_s	Storage Time				80	ns
t_f	Fall Time				30	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

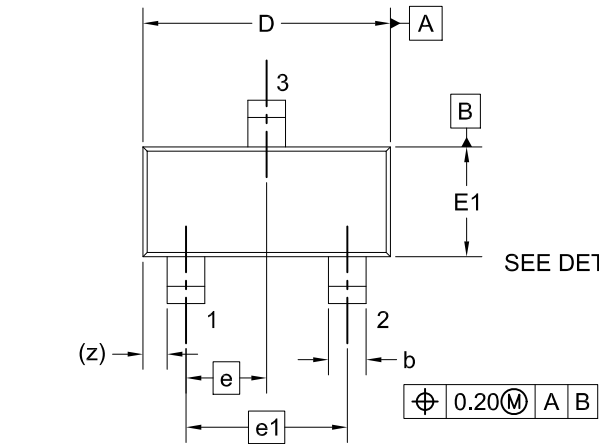


SOT-23
CASE 318BM
ISSUE A

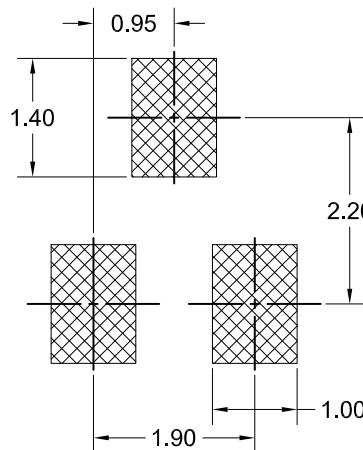
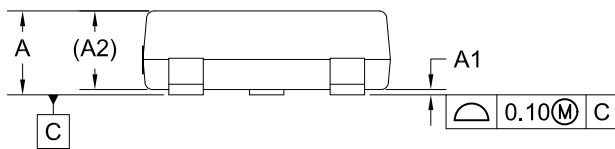
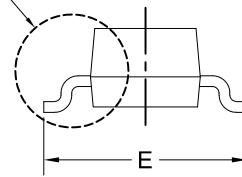
DATE 01 SEP 2021

NOTES: UNLESS OTHERWISE SPECIFIED

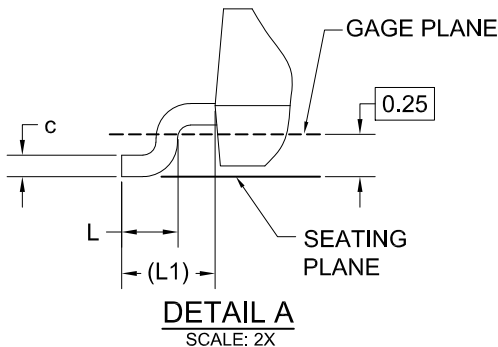
- A) REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE H.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE INCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR EXTRUSIONS.
- D) DIMENSIONING AND TOLERANCING PER ASME Y14.5M - 2009.



SEE DETAIL A

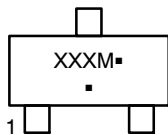


DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	---	---	1.20
A1	0.00	0.05	0.10
A2	0.93 REF		
b	0.37	0.44	0.60
c	0.08	0.15	0.23
D	2.72	2.92	3.12
E	2.10	2.40	2.70
E1	1.15	1.30	1.50
e	0.95 BSC		
e1	1.90 BSC		
L	0.20	---	---
L1	0.55 REF		
z	0.29 REF		



LAND PATTERN
RECOMMENDATION

GENERIC MARKING DIAGRAM*



- XXX = Specific Device Code
- M = Date Code
- = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

*FOR ADDITIONAL INFORMATION ON OUR PB-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

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